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Ishiang Shih was born in Taiwan. He received the B.Sc. degree in electrical engineering from Cheng Kung University, and the M.Eng. and Ph.D. degrees from the Electrical Engineering Department, McGill University, Montreal, QC, Canada, where he is currently an Associate Professor with the Electrical and Computer Engineering Department. He has been involved in the teaching of several solid-state electronics courses and IC Fabrication Laboratory. His major research activities include the growth and characterization of tellurium and selenium–tellurium crystals, growth of CuInSe<sub>2</sub> and related compounds for solar cells, thin-film transistors, and high-frequency III–V devices.

Ishiang Shih received the B.Eng. degree in electrical engineering from the National Cheng Kung University, Taiwan, and the M.Eng. and Ph.D degrees in electrical engineering from McGill University, Montreal, QC, Canada, in 1978 and 1981, respectively. He is an Associate Professor in the Department of Electrical and Computer Engineering at McGill University. His research interests lie in the areas of nanotechnology, solid-state electronic materials and devices, and electronic circuits. He has been the coauthor of more than 200 publications and more than 20 patents.